# NSN 5962-01-286-9096

Memory Microcircuit - Page 1 of 2



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# Body Length:

1.060 inches

# Body Width:

Between 0.220 inches and 0.310 inches

# **Body Height:**

Between 0.140 inches and 0.185 inches

# **Maximum Power Dissipation Rating:**

2.0 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Hermetically sealed and burn in and bipolar and programmable and monolithic and electrostatic sensitive

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

# **Output Logic Form:**

Transistor-transistor logic

# Input Circuit Pattern:

14 input

Case Outline Source And Designator:

D-8 mil-m-38510

# **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 12.0 volts power source

# Time Rating Per Chacteristic:

30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Pal

#### Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### **Terminal Type And Quantity:**

20 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

# NSN 5962-01-286-9096

Memory Microcircuit - Page 2 of 2

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